

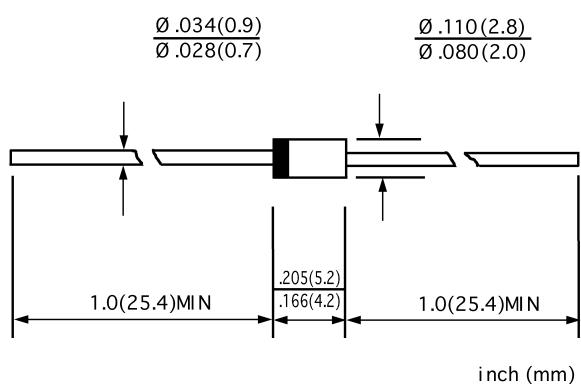
ES1F---ES1A

**VOLTAGE RANGE: 1500 --- 600 V
CURRENT: 0.7 A**

FEATURES

- ◇ Low cost
- ◇ Diffused junction
- ◇ Low leakage
- ◇ Low forward voltage drop
- ◇ High current capability
- ◇ Easily cleaned with Freon, Alcohol, Isopropanol and similar solvents
- ◇ The plastic material carries U/L recognition 94V-0

DO - 41



MECHANICAL DATA

- ◇ Case: JEDEC DO-41, molded plastic
- ◇ Terminals: Axial lead, solderable per MIL-STD-750, Method 2026
- ◇ Polarity: Color band denotes cathode
- ◇ Weight: 0.012 ounces, 0.34 grams
- ◇ Mounting position: Any

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate by 20%.

		ES1F	ES1Z	ES1	ES1A	UNITS
Maximum recurrent peak reverse voltage	V_{RRM}	1500	200	400	600	V
Maximum RMS voltage	V_{RMS}	1050	140	280	420	V
Maximum DC blocking voltage	V_{DC}	1500	200	400	600	V
Maximum average forward rectified current 9.5mm lead length, @ $T_A=75^\circ C$	$I_{F(AV)}$	0.5		0.7		A
Peak forward surge current 8.3ms single half-sine-wave superimposed on rated load @ $T_J=125^\circ C$	I_{FSM}	20.0		30.0		A
Maximum instantaneous forward voltage @ 0.5/0.7A	V_F	2.0		2.5		V
Maximum reverse current @ $T_A=25^\circ C$ at rated DC blocking voltage @ $T_A=100^\circ C$	I_R	10.0	5.0			μA
			100.0			
Maximum reverse recovery time (Note1)	t_{rr}		350			ns
Typical junction capacitance (Note2)	C_J		15			pF
Typical thermal resistance (Note3)	$R_{\theta JA}$		50			°C/W
Operating junction temperature range	T_J		-55----+150			°C
Storage temperature range	T_{STG}		-55----+150			°C

NOTE:1. Measured with $I_F=0.5A$, $I_R=1A$, $I_{rr}=0.25A$.

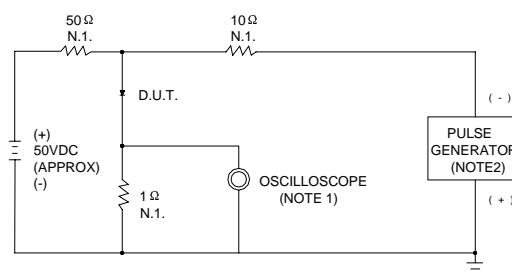
2. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.

3. Thermal resistance from junction to ambient.

ES1F---ES1A

VOLTAGE RANGE: 1500 --- 600 V
CURRENT: 0.7 A

FIG.1 – REVERSE RECOVERY TIME CHARACTERISTIC AND TEST CIRCUIT DIAGRAM



NOTES: 1. RISE TIME = 7ns MAX. INPUT IMPEDANCE = 1MΩ 22PF
2. RISE TIME = 10ns MAX. SOURCE IMPEDANCE = 50Ω

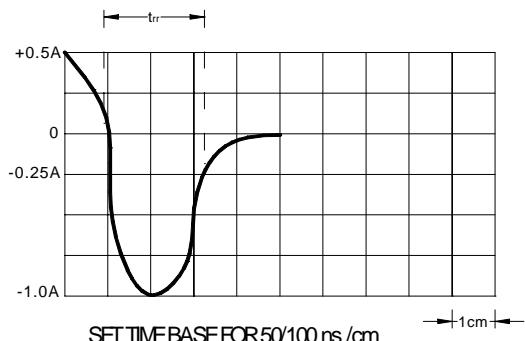
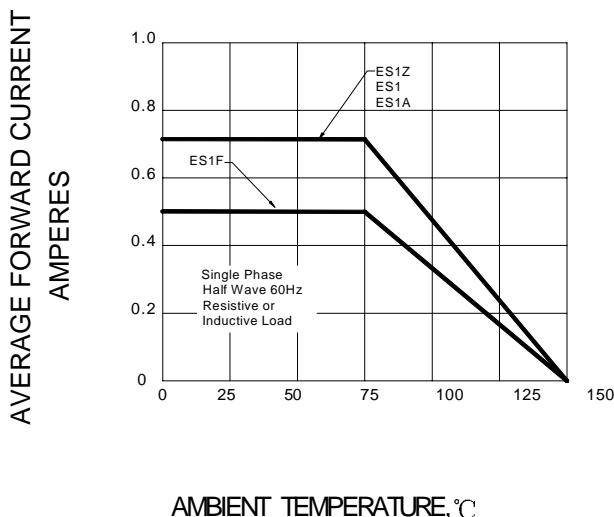
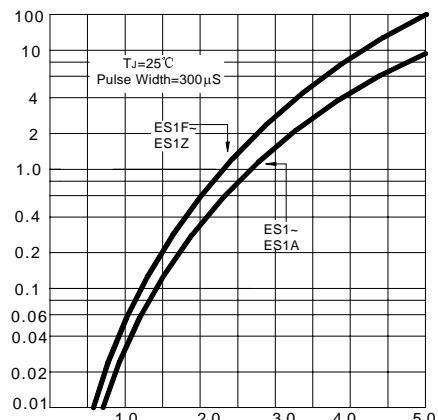


FIG.2 – FORWARD DERATING CURVE



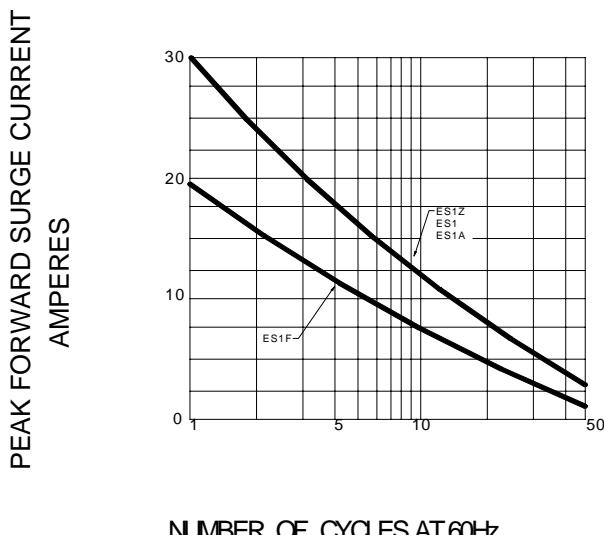
AVERAGE FORWARD CURRENT
AMPERES
INSTANTANEOUS FORWARD CURRENT
AMPERES

FIG.3 – TYPICAL FORWARD CHARACTERISTIC



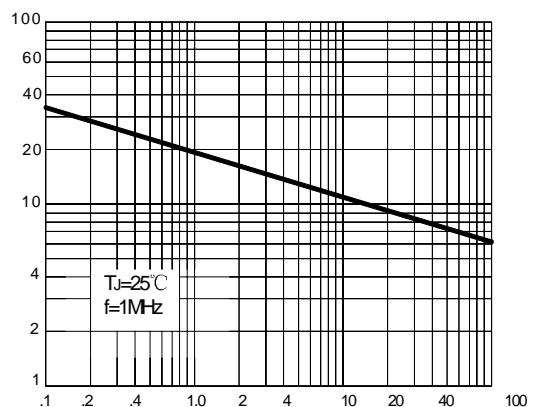
INSTANTANEOUS FORWARD CURRENT, VOLTS

FIG.4 – PEAK FORWARD SURGE CURRENT



PEAK FORWARD SURGE CURRENT
AMPERES
JUNCTION CAPACITANCE, pF

FIG.5 – TYPICAL JUNCTION CAPACITANCE



REVERSE VOLTAGE, VOLTS